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T. Young
5-15-99

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Priority Application Serial No. 08/993,663
Priority Filing Date December 18, 1997
Inventor Salman Akram et al.
Assignee Micron Technology, Inc.
Priority Group Art Unit 2812
Priority Examiner S. Mulpuri
Attorney's Docket No. MI22-1171
Title: Methods of Forming a Transistor Gate (As Amended)

PRELIMINARY AMENDMENT

To: Assistant Commissioner for Patents
Washington, D.C. 20231

From: James D. Shaurette (Tel. 509-624-4276; Fax 509-838-3424)
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AMENDMENTS

In the Title

Please replace the title with --Methods of Forming a Transistor
Gate--.

In the Specification

At p. 1, before the "Technical Field" section, insert